

Silicon Carbide (SiC) Diode – EliteSiC, TO220-2, 12 A, 650 V SiC Merged PiN-Schottky (MPS) Diode

UJ3D06512TS

Description

onsemi offers the 3rd generation of high performance SiC Merged-PiN-Schottky (MPS) diodes. With zero reverse recovery charge and 175 °C maximum junction temperature, these diodes are ideally suited for high frequency and high efficiency power systems with minimum cooling requirements.

Features

- Maximum Operating Temperature of 175 °C
- Easy Paralleling
- Extremely Fast Switching not Dependent on Temperature
- No Reverse or Forward Recovery
- Enhanced Surge Current Capability, MPS Structure
- Excellent Thermal Performance, Ag Sintered
- 100% UIS Tested
- This Device is Pb-Free, Halogen Free and is ROHS Compliant

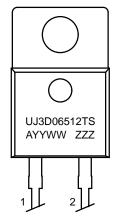
Typical Applications

- Power Converters
- Industrial Motor Drives
- Switch Mode Power Supplies
- Power Factor Correction Modules



TO220-2 CASE 340AZ

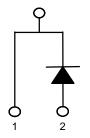
MARKING DIAGRAM



UJ3D06512TS = Specific Device Code A = Assembly Location

YY = Year WW = Work Week ZZZ = Lot ID

PIN CONNECTIONS



ORDERING INFORMATION

See detailed ordering and shipping information on page 4 of this data sheet.

UJ3D06512TS

MAXIMUM RATINGS

| Parameter | Symbol | Test Conditions | Value | Unit | |
|---|-----------------------------------|---|------------|------------------|--|
| DC Blocking Voltage | V_R | | 650 | V | |
| Repetitive Peak Reverse Voltage, T _J = 25 °C | V_{RRM} | | 650 | V | |
| Surge Peak Reverse Voltage | V_{RSM} | | 650 | V | |
| Maximum DC Forward Current | I _F | T _C = 153 °C | 12 | Α | |
| Non-repetitive Forward Surge Current Sine | I _{FSM} | $T_C = 25 {}^{\circ}\text{C}, t_p = 10 \text{ms}$ | 81 | Α | |
| Halfwave | | $T_C = 110 {}^{\circ}\text{C}, t_p = 10 \text{ms}$ | 70 | | |
| Repetitive Forward Surge Current Sine | I _{FRM} | $T_C = 25 {}^{\circ}\text{C}, t_p = 10 \text{ms}$ | 53 | Α | |
| Halfwave, D = 0.1 | | $T_C = 110 {}^{\circ}\text{C}, t_p = 10 \text{ms}$ | 32.5 | | |
| Non-repetitive Peak Forward Current | I _{F,max} | $T_C = 25 {}^{\circ}\text{C}, t_p = 10 \mu\text{s}$ | 480 | Α | |
| | | $T_C = 110 {}^{\circ}\text{C}, t_p = 10 \mu\text{s}$ | 480 | | |
| i ² t Value | ∫i ² dt | $T_C = 25 ^{\circ}\text{C}, t_p = 10 \text{ms}$ | 32.8 | A ² s | |
| | | $T_C = 110 ^{\circ}\text{C}, t_p = 10 \text{ms}$ | 24.5 | | |
| Power Dissipation | P _{Tot} | T _C = 25 °C | 187.5 | W | |
| | | T _C = 153 °C | 27.5 | | |
| Maximum Junction Temperature | $T_{J,max}$ | | 175 | °C | |
| Operating and Storage Temperature | T _J , T _{STG} | | -55 to 175 | °C | |
| Soldering Temperatures, Wavesoldering only Allowed at Leads | T _{sold} | 1.6 mm from case for 10 s | 260 | °C | |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|-----------------------------------|-----------------|-----------------|-----|-----|-----|------|
| Thermal Resistance, Junction-Case | $R_{\theta JC}$ | | _ | 0.6 | 0.8 | °C/W |

ELECTRICAL CHARACTERISTICS (T_J = +25 °C unless otherwise specified)

| Parameter | Symbol | Test Conditions | Min | Тур | Max | Unit |
|----------------------------------|----------------|--|-----|-----|------|------|
| Forward Voltage | V _F | I _F = 12 A, T _J = 25 °C | _ | 1.5 | 1.7 | V |
| | | I _F = 12 A, T _J = 150 °C | _ | 1.8 | 2.1 | |
| | | I _F = 12 A, T _J = 175 °C | _ | 1.9 | 2.25 | |
| Reverse Current | I _R | $V_R = 650 \text{ V}, T_J = 25 ^{\circ}\text{C}$ | _ | 1.4 | 80 | μΑ |
| | | V _R = 650 V, T _J = 175 °C | _ | 12 | - | |
| Total Capacitive Charge (Note 1) | Q _C | V _R = 400 V | _ | 29 | _ | nC |
| Total Capacitance | С | V _R = 1 V, f = 1 MHz | _ | 392 | - | pF |
| | | V _R = 300 V, f = 1 MHz | _ | 48 | - | |
| | | V _R = 600 V, f = 1 MHz | _ | 42 | - | 1 |
| Capacitance Stored Energy | E _C | V _R = 400 V | _ | 4.4 | _ | μJ |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

1. Q_C is independent on T_J, di_F/dt, and I_F as shown in the application note <u>AND90316/D</u>

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TYPICAL PERFORMANCE DIAGRAMS

I_F, Forward Current (A)

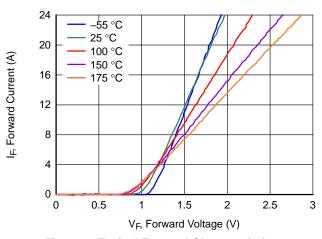


Figure 1. Typical Forward Characteristics

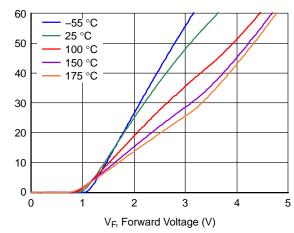


Figure 2. Typical Forward Characteristics in Surge Current

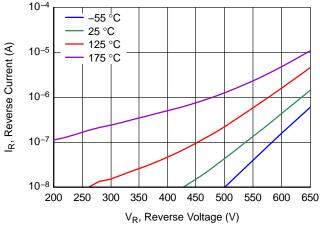


Figure 3. Typical Reverse Characteristics

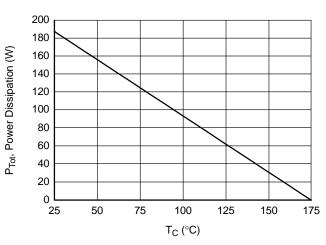


Figure 4. Power Dissipation

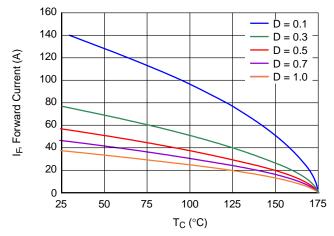


Figure 5. Diode Forward Current

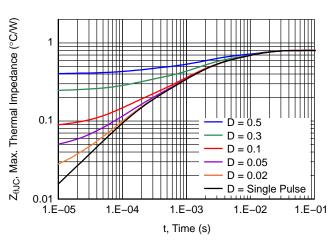


Figure 6. Maximum Transient Thermal Impedance

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TYPICAL PERFORMANCE DIAGRAMS (CONTINUED)

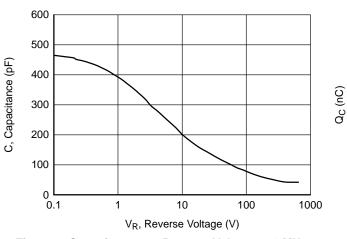


Figure 7. Capacitance vs. Reverse Voltage at 1 MHz

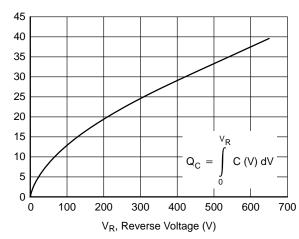


Figure 8. Typical Capacitive Charge vs. Reverse Voltage

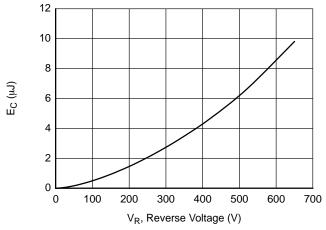


Figure 9. Typical Capacitance Stored Energy vs. Reverse Voltage

ORDERING INFORMATION

| Part Number | Marking | Package | Shipping |
|-------------|-------------|------------------------------------|-------------|
| UJ3D06512TS | UJ3D06512TS | TO220-2 (Pb-Free, Halogen Free) | 1000 / Tube |

→ 0.381(M) B

D2

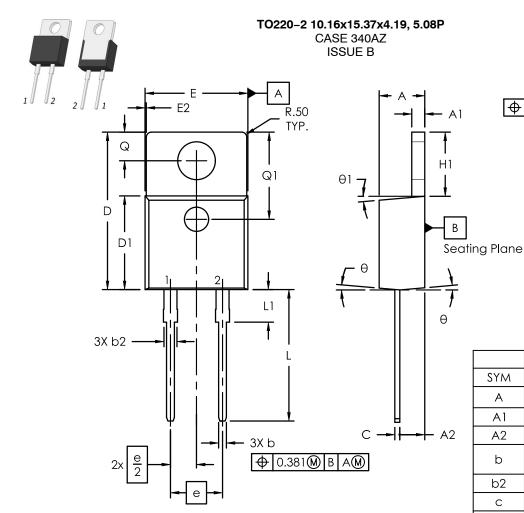


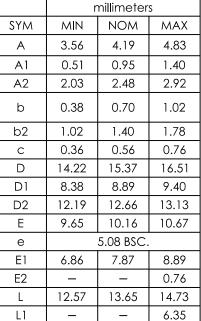
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A(M)

Ε1







ØΡ

Н1

Q

Q1

θ

θ1

3.53

5.84

2.54

8.38

3.81

6.35

2.98

8.51

5°

5°

4.09

6.86

3.43

8.64

NOTES:

R.30

- 1. Dimensioning and Tolerancing as per ASME Y14.5M, 2018.
- 2. Controlling Dimension: Millimeters
- Dimensions D and E does not include Mold Flash. These dimensions are measure at the outermost extreme of the plastic body.
- 4. Through hole diameter value = End Hole Diameter
- 5. PCB through hole pattern as per IPC-2222

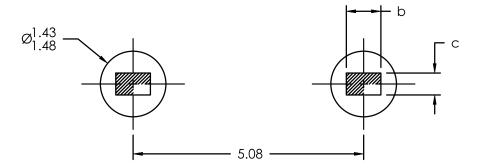
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RECOMMENDED PCB PATTERN



NOTE: LAND PATTERN AND THROUGH HOLE DIMENSIONS SERVE ONLY AS AN INITIAL GUIDE. END-USER PCB DESIGN RULES AND TOLERANCES SHOULD ALWAYS PREVAIL.

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